



High-performance polycrystalline silicon; 156mm cells; module efficency up to 13%; 3-busbar technology to increase power output

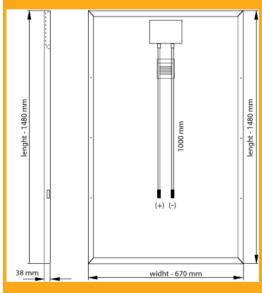












General informations

WinSolar is always careful in the choice of materials and the search for new technological solutions more innovative. Each module exceeds, through the entire production cycle, over 30 quality controls, from the selection of raw materials, production processes up to the final test operation and classification of the finished product.

The choice of materials, the high level of automation in production processes ensure excellent performance and extreme reliability over time, which is why we guarantee our modules **13** years and **25** anni of linear performance warranty covering a period of **25** year : **2,5% maximum performance degression during the first year and 0,7% p.a. for the next 24 years.**

The JB is produced in order to spare hot spot event to maximize the efficiency of the system. Thanks to the special anti-reflective coating, the glass maximizes the capture of sunlight and therefore implements the productivity of PV module also in low radiation conditions. The glass offers better resistance to dust deposits and requires less maintenanceGiven its hydrophilic. The thickness of 3.22 mm provides resistance to mechanical stress. All modules have high efficiency cells 3 bus bars that allow better collection of the current produced and increase the power of the module.







Data Sheet

Electrical Data		WNS 130 P36				
Maximum Power	P _{max}		130 Wp			
Nominal Voltage	V _{mpp}		17,1 V			
Short circuit current	I _{sc}	8,15 A				
Maximum power point current	I _{mpp}		7,65 A			
Open circuit voltage	V _{oc}		21,4 V			
Module efficiency	%		13,15%			
Performance Tolerance	P (wp)		0Wp + 5Wp			
Nr of cells			36 pcs			
Cells			Polycrystalline			
Limit values						
Maximum system voltage SCII	(V _{dc})		1000 V _{dc}			
Maximum reverse current	(A)		15 A			
NOCT (800 W/m², 20°C, AM 1.5, 1 m/s)	(°C)		+42°C +/-2°C			
Thermal characteristics						
Voltage	V _{oc}		-0,34% / °C			
Current	I _{sc}		+0,05% / °C			
Output	P _{mpp}		-0,41% / °C			
Load/dynamic load	Ра		5400 Pa			
Number of bypass diodes	Ν.		3			
Operating range	Ν.		-40°C a +85°C			
Physical Characteristics						
Dimensions (L x W x H)	(mm)		1480 x 670 x 45 mm			
Weight	(Kg totali)		14 Kg			
Junction Box	Protection degree IP67 - 3 bypass diodes - MC4 connector compatible					
Cables	Conductor sectio	Conductor section 4 mm ² , length 1 m (MC4)				
Irradiance Dependence		1000 W/m ²	800 W/m²	600 W/m ²	400 W/m	
	I _{sc}	0 %	-19,6 %	-39,5 %	-59,2 %	
	V _{oc}	0 %	-1,38 %	-3,05 %	-5,9 %	
General data						
Frontside	Low-reflection 3,2 mm tempered glass					
Frame	45 mm silver anodized alluminium frame					
Cells	36 polycrystalline	36 polycrystalline high efficiency cells 156 mm x 156 mm (6")				
Elements	Made in EU elem	ients (glass, frai	me, cables)			
Certifications						







Ammonia NH resistance certificate

CE 🍂





